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Inclosure Material:

Metal

Overall Length:

0.250 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.359 inches

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-39

Electrode Internally-electrically Connected To Case:

Drain

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

90.0 drain to source voltage and 15.0 gate to source voltage

Current Rating Per Characteristic:

2.00 amperes drain current and 2.00 milliamperes gate current

Power Rating Per Characteristic:

6.2 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/547 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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